TOSHIBA Transistor Silicon NPN Epitaxial Type

2SC4684

Strobe Flash Applications Medium Power Amplifier Applications

• High DC current gain

: h_{FE} (1) = 800 to 3200 (V_{CE} = 2 V, I_{C} = 0.5 A)

: $h_{FE}(2) = 250 \text{ (VCE} = 2 \text{ V, IC} = 4 \text{ A)}$

· Low collector saturation voltage

: VCE (sat) = 0.5 V (max) (IC = 4 A, IB = 40 mA)

• High power dissipation

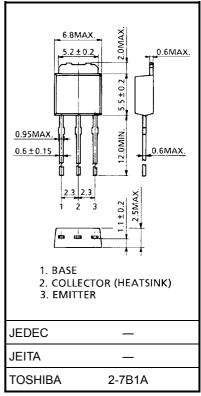
: $P_C = 10 \text{ W} \text{ (Tc} = 25^{\circ}\text{C)}, P_C = 1.0 \text{ W} \text{ (Ta} = 25^{\circ}\text{C)}$

Maximum Ratings (Ta = 25°C)

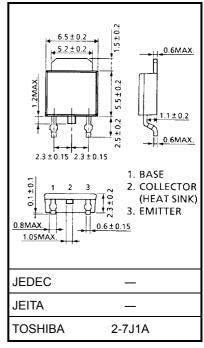
Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V_{CBO}	50	V	
Collector-emitter voltage		V _{CES}	40	V	
		V_{CEO}	20		
Emitter-base voltage		V_{EBO}	8	>	
Collector current	DC	Ic	5	А	
	Pulse (Note)	I _{CP}	8		
Base current		ΙΒ	0.5	Α	
Collector power dissipation	Ta = 25°C	Pc	1.0	W	
	Tc = 25°C	FC	10		
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	−55 to 150	°C	

Note: Pulse test: Pulse width = 10 ms (max), duty cycle = 30% (max)

Unit: mm



Weight: 0.36 g (typ.)



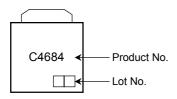
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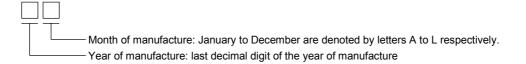
Electrical Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	V _{CB} = 50 V, I _E = 0	_	_	100	nA
Emitter cut-off current	I _{EBO}	V _{EB} = 8 V, I _C = 0	_	_	100	nA
Collector-emitter breakdown voltage	V_{CEO}	I _C = 10 mA, I _B = 0	20	_	_	٧
DC current gain	h _{FE (1)}	V _{CE} = 2 V, I _C = 0.5 A	800	_	3200	
	h _{FE (2)}	V _{CE} = 2 V, I _C = 4 A	250	_	_	
Collector-emitter saturation voltage	V _{CE (sat)}	I _C = 4 A, I _B = 40 mA	_	_	0.5	V
Base-emitter voltage	V _{BE}	V _{CE} = 2 V, I _C = 4 A	_	_	1.2	V
Transition frequency	f _T	V _{CE} = 2 V, I _C = 0.5 A	_	150	_	MHz
Collector output capacitance	C _{ob}	V _{CB} = 10 V, I _E = 0, f = 1 MHz	_	45	_	pF

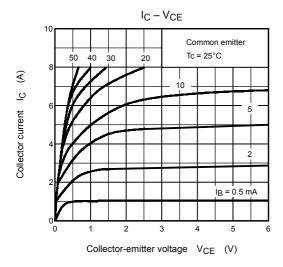
Marking

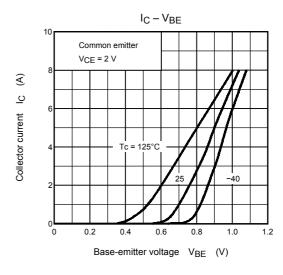


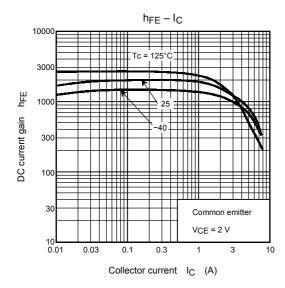
Explanation of Lot No.

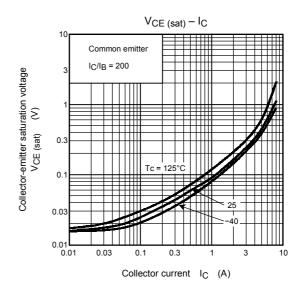


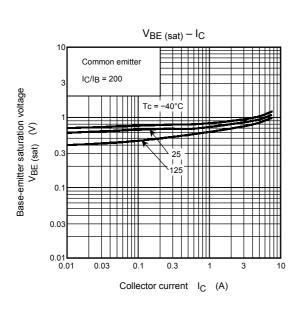
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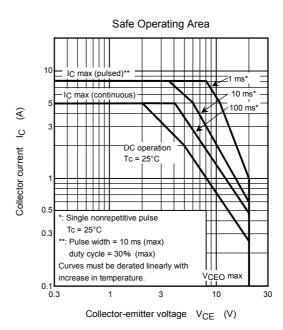












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